TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LVX245F, TC74LVX245FT

Octal Bus Transceiver

The TC74LVX245F/ FT is a high-speed CMOS octal bus transceiver fabricated using silicon gate CMOS technology. Designed for use in 3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

These devices are suitable for low-voltage and battery operated systems.

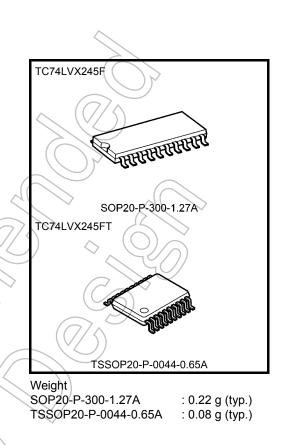
It is intended for two-way asynchronous communication between data busses.

The direction of data transmission is determined by the level of the DIR input. The enable input (\overline{G}) can be used to disable the device so that the busses are effectively isolated.

All inputs are equipped with protection circuits against static discharge.

Features (Note)

- High-speed: t_{pd} = 4.7 ns (typ.) (V_{CC} = 3.3 V)
- Low power dissipation: I_{CC} = 4 μA (max) (Ta = 25°C)
- Input voltage level: $V_{IL} = 0.8 V (max) (V_{CC} = 3 V)$ $V_{IH} = 2.0 V (min) (V_{CC} = 3 V)$
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Low noise: V_{OLP} = 0.8 V (max)
- Pin and function compatible with 74HC245



Note: Do not apply a signal to any bus pins when it is in the output mode. Damage may result. All floating (high impedance) bus pins must have their input levels fixed by means of pull-up or pull-down resistors.

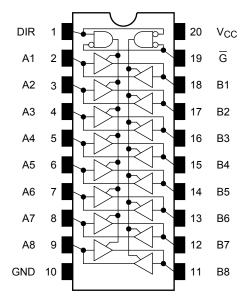
A parasitic diode is formed between the bus and V_{CC} terminals. Therefore bus terminal can not be used to interface 5-V to 3-V systems directly.

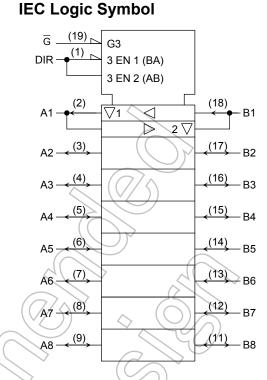


Start of commercial production 1993-01

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Pin Assignment (top view)





Truth Table

Inputs		Outputs	Function			
G	DIR	Outputs	A-Bus	B-Bus		
L	L	A = B	Output	Input		
L	Н	B = A	Input	Output		
Н	Х	Z	High impedance			

X: Don't care

Z: High impedance

Absolute Maximum Ratings (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage range	Vcc	-0.5 to 7.0	V
DC input voltage (DIR, G)	VIN	-0.5 to 7.0	V
DC bus I/O voltage	NVO	-0.5 to V_{CC} + 0.5	V
Input diode current	<u> </u>	-20	mA
Output diode current	IOK	±20	mA
DC output current	TOUT	±25	mA
DC V _{CC} /ground current	Icc	±75	mA
Power dissipation	PD	180	mW
Storage temperature	T _{stg}	–65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	2.0 to 3.6	V
Input voltage (DIR, \overline{G})	V _{IN}	0 to 5.5	V
Bus I/O voltage	V _{I/O}	0 to V _{CC}	V
Operating temperature	T _{opr}	-40 to 85	°C
Input rise and fall time	dt/dv	0 to 100	ns/V

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs and bus inputs must be tied to either V_{CC} or GND. Please connect both bus inputs and the bus outputs with V_{CC} or GND when the I/O of the bus terminal changes by the function. In this case, please note that the output is not short-circuited.

Electrical Characteristics

DC Characteristics

Characteristics		Symbol			\bigcirc	Ta = 25°C		Ta = -40 to 85°C		Unit	
					V _{CC} (V)	Min	Тур.	Max	Min	Max	
					2.0	1.5	(\mathcal{H})) -	1.5	_	
	H-level	VIH			3.0	2.0		/	2.0		
Input voltage					3.6	2.4			2.4		v
input voltage						$\left \right\rangle$	//-	0.5	—	0.5	v
	L-level	VIL					_	0.8	—	0.8	
			$(C \uparrow$		3.6			0.8	—	0.8	
	H-level	VoH	V _{IN} = V _{IH} or V _{IL}	I _{OH} = –50 μA	2.0	1.9	2.0	_	1.9	_	
				I _{OH} = -50 μA	3.0	2.9	3.0		2.9	_	
Output voltage			\mathcal{D}	I _{OH} = -4 mA	3.0	2.58		_	2.48	_	V
Output voitage		Vol	7	loL = 50 μA	2.0	_	0	0.1	—	0.1	v
	L-level		V _{IN} = V _{IH} or V _{IL}	l _{OL} = 50 μA	3.0	_	0	0.1	_	0.1	
	~			$I_{OL} = 4 \text{ mA}$	3.0	_	—	0.36	_	0.44	
3-State output Off-state current I_{OZ} $V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or } GND$		3.6	_	—	±0.25		±2.5	μΑ			
Input leakage cur	rent	I_{IN} $V_{IN} = 5.5 V \text{ or GND}$		3.6			±0.1	_	±1.0	μA	
Quiescent supply current I _{CC} V _{IN} = V _{CC} or GND		3.6			4.0	—	40.0	μA			

AC Characteristics (input: $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol Test Condition				Ta = 25°C			Ta = -40 to 85°C		Unit
			V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Min	Max	
Propagation delay time	+		2.7	15	_	6.1	10.7	1.0	13.5	ns
	t _{pLH}			50	_	8.6 <	14.2	1.0	17.0	
	t		3.3 ± 0.3	15		4.7	6.6	1.0	8.0	
	tpHL		3.3 ± 0.3	50	_	7.2	10.1	0.1	11.5	
	t _{pZL}	$R_L = 1 \ k\Omega$	2.7	15		9,0	16.9	1.0	20.5	· ns
Output enable time				50	$\langle \langle \rangle$	11.5	20.4	1.0	24.0	
	t _{pZH}		3.3 ± 0.3	15	- 2	7.1	11.0	1.0	13.0	
				50	_(9.6	14.5	1.0	16.5	
Output disable time	t _{pLZ}	$R_L = 1 k\Omega$	2.7	50		11.5	18.0	1.0	21.0	ns
	t _{pHZ}	IVL - 1 K22	$\textbf{3.3}\pm\textbf{0.3}$	50 <		9.6	12.8	0.10	14:5	115
Output to output skew	t _{osLH}	(Note 1)	2.7	50			1.5	\leq	1.5	ns
	t _{osHL}	(Note I)	$\textbf{3.3}\pm\textbf{0.3}$	50	\mathcal{H}	$-\Diamond$	1.5		1.5	115
Input capacitance	CIN	DIR, \overline{G}	((Note 2)		4	10	GC/	10	pF
Bus input capacitance	C _{I/O}	An, Bn	-C	\mathbb{Z}^{\sim}	_	8		\geq _		pF
Power dissipation capacitance	C _{PD}			(Note 3)	_	21	$\langle \mathcal{A} \rangle$	—	_	pF

Note 1: Parameter guaranteed by design.

(tosLH = |tpLHm - tpLHn|, tosHL = |tpHLm - tpHLn|)

Note 2: Parameter guaranteed by design.

Note 3: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

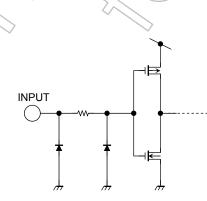
Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 (per bit)$

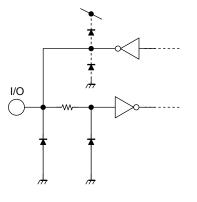
Noise Characteristics (Ta = 25° C, input: tr = tf = 3 ns, CL = 50 pF)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Limit	Unit
Quiet output maximum dynamic V_{OL}	VOLP	-	3.3	0.5	0.8	V
Quiet output minimum dynamic VOL	Volv		3.3	-0.5	-0.8	V
Minimum high level dynamic input voltage V _{IH}	VIHD	→ –	3.3	_	2.0	V
Maximum low level dynamic input voltage V _{IL}	VILD	_	3.3		0.8	V

Input Equivalent Circuit



Bus Terminal Equivalent Circuit (An, Bn)

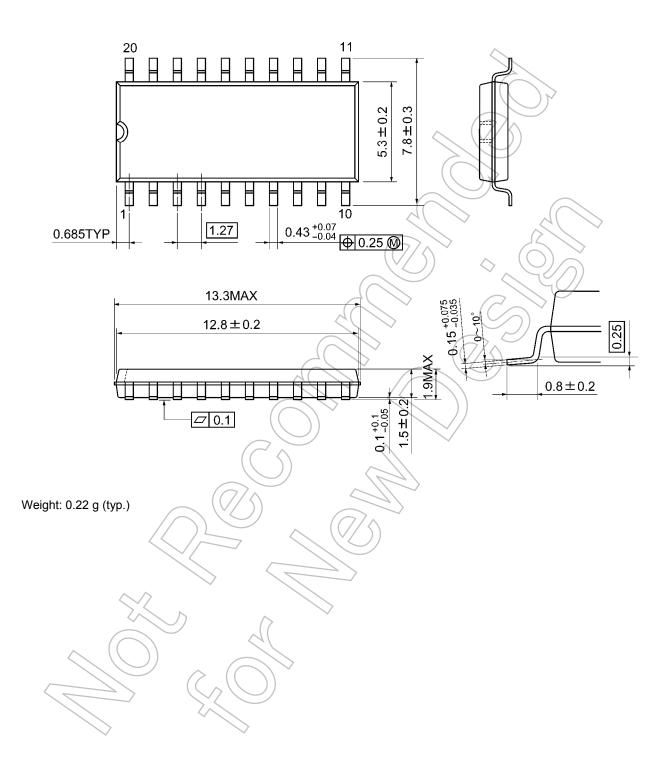




Package Dimensions

SOP20-P-300-1.27A

Unit: mm

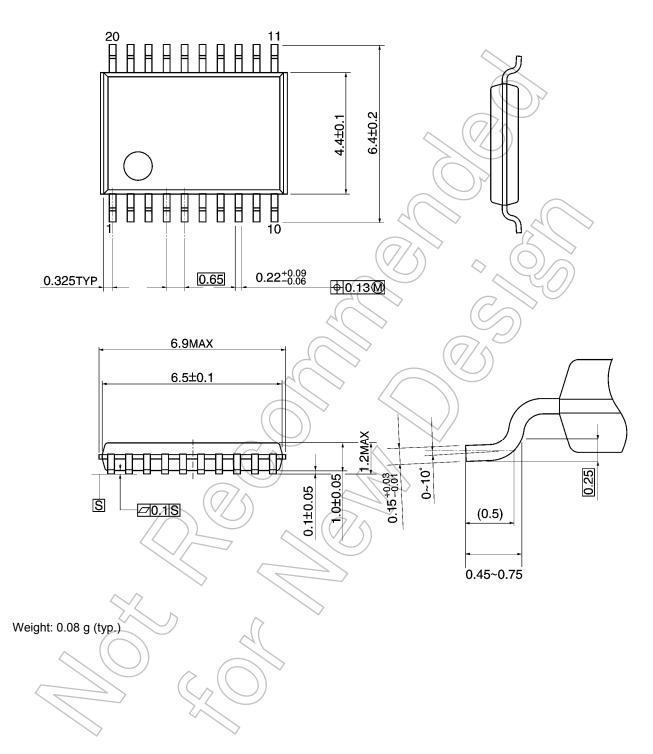


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Package Dimensions

TSSOP20-P-0044-0.65A

Unit: mm



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